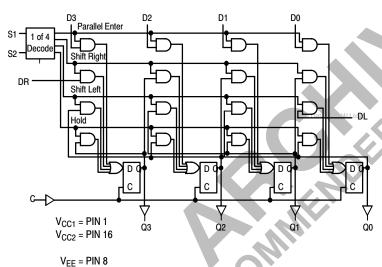
Four Bit Universal Shift Register

The MC10141 is a four—bit universal shift register which performs shift left, or shift right, serial/parallel in, and serial/parallel out operations with no external gating. Inputs S1 and S2 control the four possible operations of the register without external gating of the clock. The flip—flops shift information on the positive edge of the clock. The four operations are stop shift, shift left, shift right, and parallel entry of data. The other six inputs are all data type inputs; four for parallel entry data, and one for shifting in from the left (DL) and one for shifting in from the right (DR).

- $P_D = 425 \text{ mW typ/pkg (No Load)}$
- $f_{Shift} = 200 \text{ MHz typ}$
- t_r , $t_f = 2.0$ ns typ (20%–80%)

LOGIC DIAGRAM



TRUTH TABLE

SEL	ECT		OUTPUTS					
S1	S2	OPERATING MODE	Q0 _{n+1}	Q1 _{n+1}	Q2 _{n+1}	Q3 _{n+1}		
L	L	Parallel Entry	D0	D1	D2	D3		
L	Н	Shift Right*	Q1 _n	Q2 _n	Q3 _n	DR		
Н	L	Shift Left*	DL	Q0 _n	Q1 _n	Q2 _n		
Н	Н	Stop Shift	Q0 _n	Q1 _n	Q2 _n	Q3 _n		

^{*}Outputs as exist after pulse appears at "C" input with input conditions as shown. (Pulse = Positive transition of clock input).



ON Semiconductor

http://onsemi.com

MARKING DIAGRAMS



CDIP-16 L SUFFIX CASE 620 MC10141L AWLYYWW



PDIP-16 P SUFFIX CASE 648





PLCC-20 FN SUFFIX CASE 775

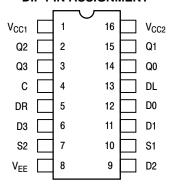


A = Assembly Location

WL = Wafer Lot

YY = Year WW = Work Week

DIP PIN ASSIGNMENT

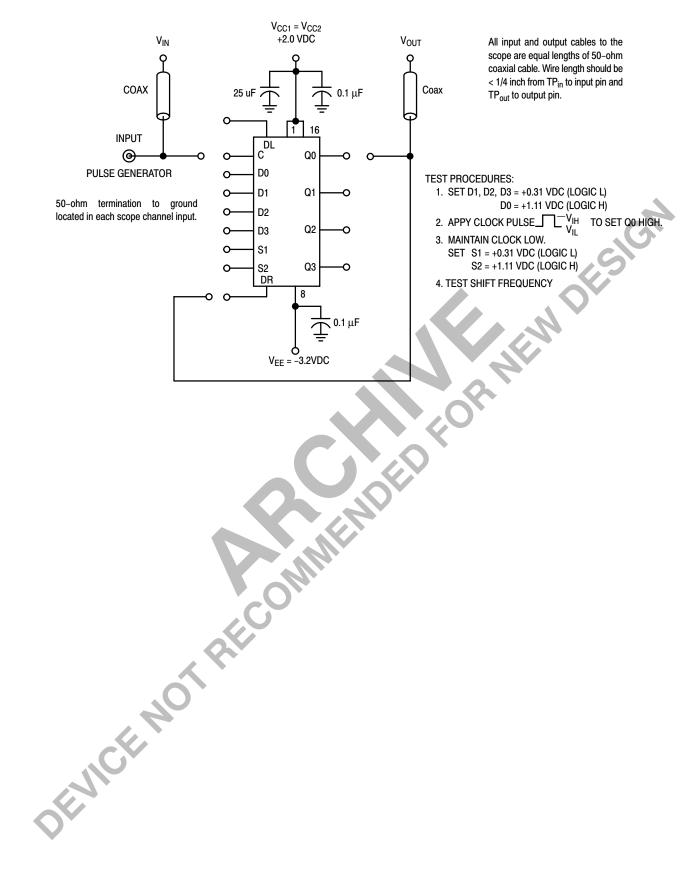


Pin assignment is for Dual-in-Line Package.
For PLCC pin assignment, see the Pin Conversion Tables on page 18 of the ON Semiconductor MECL Data Book (DL122/D).

ORDERING INFORMATION

Device	Package	Shipping		
MC10141L	CDIP-16	25 Units / Rail		
MC10141P	PDIP-16	25 Units / Rail		
MC10141FN	PLCC-20	46 Units / Rail		

SHIFT FREQUENCY TEST CIRCUIT



ELECTRICAL CHARACTERISTICS

$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	+25°C Typ 82 2.9	Max 102 220 220 245 265 -0.810 -1.650 -1.630 -1.630 -1.630 3.8	0.3 -0.890 -1.825 -0.910 -0.910 -0.910 -0.910	5°C Max 112 220 220 245 265 -0.700 -1.615 -1.595 -1.595 -1.595 -1.595 4.2	μ.Α.Α.Α.Α.Α.Α.Α.Α.Α.Α.Α.Α.Α.Α.Α.Α.Α.Α.Α
Power Supply Drain Current	2.9	220 220 245 265 -0.810 -1.650 -1.630 -1.630 -1.630 -1.630	0.3 -0.890 -1.825 -0.910 -0.910 -0.910 -0.910 2.0 2.5	220 220 245 265 -0.700 -1.615 -1.595 -1.595 -1.595	μ.Α. V
Input Current	2.9	220 220 245 265 -0.810 -1.650 -1.630 -1.630 -1.630	-0.890 -1.825 -0.910 -0.910 -0.910 -0.910 2.0 2.5	220 220 245 265 -0.700 -1.615 -1.595 -1.595 -1.595	µА V V V
Coutput Voltage	O	220 245 265 -0.810 -1.650 -1.630 -1.630 -1.630 -1.630	-0.890 -1.825 -0.910 -0.910 -0.910 -0.910 2.0 2.5	220 245 265 -0.700 -1.615 -1.595 -1.595 -1.595	μν V V
Threshold Voltage Logic 1 Voh Sand Logic 1 Voh Voh Sand Logic 1 Voh	O	245 265 -0.810 -1.650 -1.630 -1.630 -1.630 -1.630	-0.890 -1.825 -0.910 -0.910 -0.910 -0.910 2.0 2.5	245 265 -0.700 -1.615 -1.595 -1.595 -1.595 -1.595	V
A A A A A A A A A A	O	265 -0.810 -1.650 -1.630 -1.630 -1.630 -1.630	-0.890 -1.825 -0.910 -0.910 -0.910 -0.910 2.0 2.5	265 -0.700 -1.615 -1.595 -1.595 -1.595 -1.595	V
Output Voltage Logic 1 V _{OH} 3 -1.060 -0.890 -0.960 Output Voltage Logic 0 V _{OL} 3 -1.890 -1.675 -1.850 Threshold Voltage Logic 1 V _{OHA} (Note 1.) 3 -1.080 (Note 1.) -0.980 (Note 1.) Threshold Voltage Logic 0 V _{OLA} (Note 1.) 3 -1.080 (Note 1.) -0.980 (Note 1.) Switching Times (Note 1.) (SOΩ (Note 1.)) 3 1.7 (Note 1.) -1.655 (Note 1.) Switching Times (SoΩ (Note 1.)) (SOΩ (Note 1.)) 3 1.7 (Note 1.) 3.9 (Note 1.) Switching Times (SoΩ (Note 1.)) 1.655 (Note 1.) -1.655 (Note 1.) -1.655 (Note 1.) Switching Times (SoΩ (Note 1.)) 1.2 (Note 1.) 3 1.7 (Note 1.) 3.9 (Note 1.) Switching Times (SoΩ (Note 1.)) 1.2 (Note 1.) 1.4 (Note 1.) 1.7 (Note 1.) 1.8 (Note 1.) Switching Times (SoΩ (Note 1.)) 1.2 (Note 1.) 1.4 (Note 1.) 1.7 (Note 1.) 1.8 (Note 1.) Switching Times (SoΩ (Note 1.)) 1.2 (Note 1.) 1.2 (Note 1.) 1.8 (Note 1.) 1.8 (N	O	-1.630 -1.630 -1.630 -1.630 -1.630	-0.890 -1.825 -0.910 -0.910 -0.910 -0.910 2.0 2.5	-1.615 -1.595 -1.595 -1.595 -1.595	V
Output Voltage Logic 0 V _{OL} 3 -1.890 -1.675 -1.850 Threshold Voltage Logic 1 V _{OHA} (Note 1.) 3 -1.080 -0.980 -0.980 -0.980 -0.980 3 -1.080 3 -1.080 -0.980 -0.980 -0.980 Threshold Voltage Logic 0 V _{OLA} 3 (Note 1.) -1.655 -1.655 -1.655 -1.655 -1.655 -1.655 -1.655 -1.655 Switching Times (bad) (50Ω Load) Load) Load) Load) Propagation Delay Setup Tlme (t _{setup}) t ₁₂₊₄₊ 14 2.5 -1.55 -1.655 -1.655 -1.655 -1.655 -1.655 -1.655 5.0 Load) 1.8 -1.655 -1.65	O	-1.630 -1.630 -1.630 -1.630 -1.630	-1.825 -0.910 -0.910 -0.910 -0.910 2.0 2.5	-1.615 -1.595 -1.595 -1.595 -1.595	V
Threshold Voltage Logic 1 (Note 1.) 3 -1.080 -0.98	O	-1.630 -1.630 -1.630 -1.630	-0.910 -0.910 -0.910 -0.910 -2.910	-1.595 -1.595 -1.595 -1.595	V
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	O	-1.630 -1.630 -1.630	-0.910 -0.910 -0.910 -0.910	-1.595 -1.595 -1.595	V
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	O	-1.630 -1.630 -1.630	-0.910 -0.910 2.0 2.5	-1.595 -1.595 -1.595	
Threshold Voltage Logic 0 V_{OLA} 3 -1.080 -0.980 Threshold Voltage Logic 0 V_{OLA} 3 -1.655 -1.655 -1.655 -1.655 -1.655 -1.655 Switching Times (50Ω) Load) Propagation Delay t_{4+3+} 3 1.7 3.9 1.8 2.5 t_{10+4+} 14 2.5 t_{10+4+} 14 5.5 t_{10+4+} 14 1.5 t_{10+4+} 15 1.5 t_{10} 1.5 Rise Time $(20 \text{ to } 80\%)$ t_{3+} 3 t_{10} 3.4 t_{11} 1.1 Fall Time $(20 \text{ to } 80\%)$ t_{3-} 3 t_{10} 3.4 t_{11} 1.5 t_{10} 1.5 t_{10} 1.5 t_{10} 1.7 t_{10} 1.7 t_{10} 1.8 t_{10} 1.9 t_{10	O	-1.630 -1.630 -1.630	2.0 2.5	-1.595 -1.595 -1.595	
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	O	-1.630 -1.630 -1.630	2.5	-1.595 -1.595 -1.595	
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	O	-1.630 -1.630	2.5	-1.595 -1.595 -1.595	,
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	O	-1.630	2.5	-1.595	ı
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	O		2.5		1
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	O	3.8	2.5	4.2	'
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	O	3.8	2.5	4.2	
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	0				
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	20				
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	2.0		5.5 1.5		
Fall Time (20 to 80%) t_{3-} 3 1.0 3.4 1.1 Shift Frequency f_{shift} 150 150 V_{IL} P2	2.0	3.3	1.1	3.6	
Shift Frequency f_{shift} 150 150 . These tests to be performed in sequence as shown.	2.0	3.3	1.1	3.6	
. These tests to be performed in sequence as shown. P1 VIH VIL P2	200		150		N
2. See shift frequency test circuit for test procedures. 3. Reset to zero before performing test. 4. Reset to one before performing test.					

ELECTRICAL CHARACTERISTICS (continued)

				TEST VOL	TAGE VALU	JES (Volts)					
(@ Test Tem	perature	V _{IHmax}	V _{ILmin}	V _{IHAmin}	V _{ILAmax}	V _{EE}				
		–30°C	-0.890	-1.890	-1.205	-1.500	-5.2				
		+25°C	-0.810	-1.850	-1.105	-1.475	-5.2				
		+85°C	-0.700	-1.825	-1.035	-1.440	-5.2				
		Pin	TEST VOL	TAGE APP	LIED TO P	INS LISTED	BELOW				
Characteristic	Symbol	Under Test	V _{IHmax}	V _{ILmin}	V _{IHAmin}	V _{ILAmax}	V _{EE}	P1	P2	Р3	(V _{CC}) Gnd
Power Supply Drain Current	ΙE	8					8				1, 16
Input Current	l _{inH}	5 6 7 4	5 6 7 4				8 8 8				1, 16 1, 16 1, 16 1, 16
	l _{inL}	12	4,5,6,7,9, 10,11,13	12			8				1, 16
Output Voltage Logic 1	V _{OH}	3	6				8	4			1, 16
Output Voltage Logic 0	V _{OL}	3					8	4			1, 16
Threshold Voltage Logic 1	V _{OHA} (Note 1.)	3 3 3 3	6 6	Note 3. Note 3.	6	7	8 8 8	4 4	4	4	1, 16 1, 16 1, 16 1, 16
Threshold Voltage Logic 0	V _{OLA} (Note 1.)	3 3 3 3	6	Note 4. Note 4.		6 7	8888	4	4	4	1, 16 1, 16 1, 16 1, 16
Switching Times (50Ω Load)					\		-3.2 V				+2.0 V
Propagation Delay Setup TIme (t _{setup}) Hold Time (t _{hold}) Rise Time (20 to 80%)	t ₄₊₃₊ t ₁₂₊₄₊ t ₁₀₊₄₊ t ₄₊₁₂₊	3 14 14 14	C				8 8 8 8				1, 16 1, 16 1, 16 1, 16
(t ₃₊	3					_				1, 16
Fall Time (20 to 80%) Shift Frequency	t ₃₋	3	Note 2.				8 8				1, 16 1, 16
These tests to be performed	f _{shift}		D1		P2		V _{IHA}	P3 [<u> </u>	1, 16

^{2.} See shift frequency test circuit for test procedures.

Each MECL 10,000 series circuit has been designed to meet the dc specifications shown in the test table, after thermal equilibitum has been established. The circuit is in a test socket or mounted on a printed circuit board and transverse air flow greater than 500 linear fpm is maintained. Outputs are terminated through a 50-ohm resistor to -2.0 volts. Test procedures are shown for only one gate. The other gates are tested in the same manner.

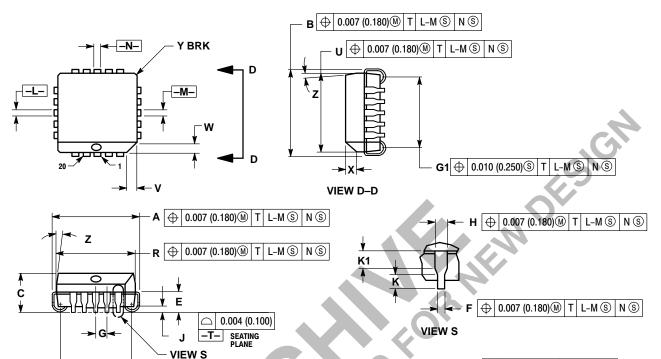
^{3.} Reset to zero before performing test.

^{4.} Reset to one before performing test.

PACKAGE DIMENSIONS

PLCC-20 **FN SUFFIX**

PLASTIC PLCC PACKAGE CASE 775-02 ISSUE C



NOTES:

G1 ⊕ 0.010 (0.250)③ T L-M ⑤ N ⑤

OF MICE. NOT PERSON

- OTES:

 1. DATUMS -L-, -M-, AND -N- DETERMINED WHERE TOP OF LEAD SHOULDER EXITS PLASTIC BODY AT MOLD PARTING LINE.

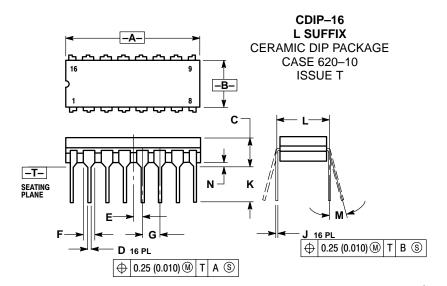
 2. DIMENSION G1, TRUE POSITION TO BE MEASURED AT DATUM -T-, SEATING PLANE.

 3. DIMENSIONS R AND U DO NOT INCLUDE MOLD FLASH. ALLOWABLE MOLD FLASH IS 0.010 (0.250) PER SIDE.

 4. DIMENSIONING AND TOLERANCING PER ANSI V14 5M 1982
- Y14.5M, 1982. CONTROLLING DIMENSION: INCH.
- THE PACKAGE TOP MAY BE SMALLER THAN THE PACKAGE BOTTOM BY UP TO 0.012 (0.300). DIMENSIONS R AND U ARE DETERMINED AT THE OUTERMOST EXTREMES OF THE PLASTIC BODY EXCLUSIVE OF MOLD FLASH, TIE BAR BURRS, GATE BURRS AND INTERLEAD FLASH, BUT INCLUDING ANY MISMATCH BETWEEN THE TOP AND BOTTOM OF THE PLASTIC BODY.
- DIMENSION H DOES NOT INCLUDE DAMBAR PROTRUSION OR INTRUSION. THE DAMBAR PROTRUSION(S) SHALL NOT CAUSE THE H DIMENSION TO BE GREATER THAN 0.037 (0.940). THE DAMBAR INTRUSION(S) SHALL NOT CAUSE THE H DIMENSION TO BE SMALLER THAN 0.025 (0.635).

	INC	HES	MILLIM	ETERS
DIM	MIN	MAX	MIN	MAX
Α	0.385	0.395	9.78	10.03
В	0.385	0.395	9.78	10.03
С	0.165	0.180	4.20	4.57
Е	0.090	0.110	2.29	2.79
F	0.013	0.019	0.33	0.48
G	0.050	BSC	1.27	BSC
Н	0.026	0.032	0.66	0.81
J	0.020		0.51	
K	0.025		0.64	
R	0.350	0.356	8.89	9.04
U	0.350	0.356	8.89	9.04
٧	0.042	0.048	1.07	1.21
W	0.042	0.048	1.07	1.21
X	0.042	0.056	1.07	1.42
Υ		0.020		0.50
Z	2°	10°	2°	10 °
G1	0.310	0.330	7.88	8.38
K1	0.040		1.02	

PACKAGE DIMENSIONS



NOTES:

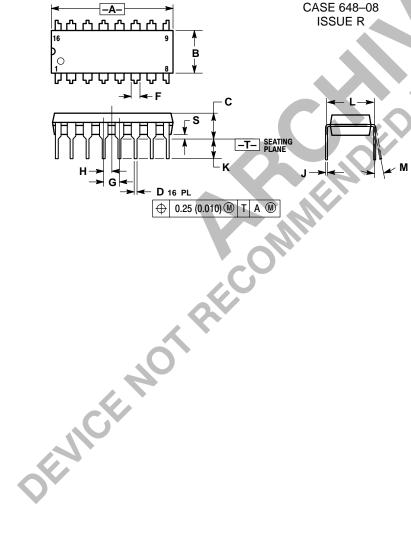
- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 CONTROLLING DIMENSION: INCH.
 DIMENSION LTO CENTER OF LEAD WHEN CONTROLLING DIMENSION LTO CENTER OF LEAD WHEN

- FORMED PARALLEL

 DIMENSION F MAY NARROW TO 0.76 (0.030)
 WHERE THE LEAD ENTERS THE CERAMIC
 BODY.

	INC	HES	MILLIN	IETERS			
DIM	MIN MAX		MIN	MAX			
Α	0.750	0.785	19.05	19.93			
В	0.240	0.240 0.295 6.10					
С		0.200		5.08			
D	0.015	0.020	0.39	0.50			
E	0.050	BSC	1.27 BSC				
F	0.055	0.065	1.40 1.65				
G	0.100	BSC	2.54 BSC				
Н	0.008	0.015	0.21	0.38			
K	0.125	0.170	3.18	4.31			
L	0.300	BSC	7.62 BSC				
M	0 °	15°	0 °	15°			
N	0.020	0.040	0.51	1.01			

PDIP-16 **P SUFFIX** PLASTIC DIP PACKAGE CASE 648-08 ISSUE R



- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.
 3. DIMENSION L TO CENTER OF LEADS WHEN FORMED PARALLEL.
 4. DIMENSION B DOES NOT INCLUDE MOLD FLASH.
 5. ROUNDED CORNERS OPTIONAL

	INC	HES	MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.740	0.770	18.80	19.55
В	0.250	0.270	6.35	6.85
C	0.145	0.175	3.69	4.44
D	0.015	0.021	0.39	0.53
F	0.040	0.70	1.02	1.77
G	0.100 BSC 2.54 BSC			
Н	0.050	BSC	1.27	BSC
J	0.008	0.015	0.21	0.38
K	0.110	0.130	2.80	3.30
L	0.295	0.305	7.50	7.74
M	0°	10 °	0°	10 °
S	0.020	0.040	0.51	1.01

Notes





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